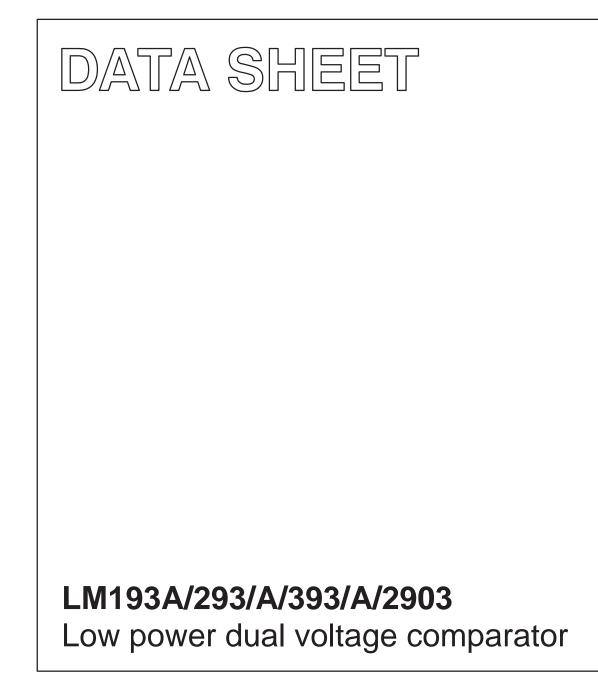
INTEGRATED CIRCUITS



Product data Supersedes data of 2002 Jan 22 2002 Jul 12





LM193A/293/A/393/A/2903

DESCRIPTION

The LM193 series consists of two independent precision voltage comparators with an offset voltage specification as low as 2.0 mV max. for two comparators which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible, and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

The LM193 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM193 series will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

FEATURES

- Wide single supply voltage range 2.0 V_{DC} to 32 V_{DC}, or dual supplies \pm 1.0 V_{DC}, to \pm 16 V_{DC}
- Very low supply current drain (0.8 mA) independent of supply voltage (2.0 mW/comparator at 5.0 V_{DC})
- Low input biasing current 25 nA
- Low input offset current ±5 nA and offset voltage ±2 mV
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Low output 250 mV at 4 mA saturation voltage
- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems

APPLICATIONS

- A/D converters
- Wide range VCO
- MOS clock generator
- High voltage logic gate
- Multivibrators

PIN CONFIGURATION

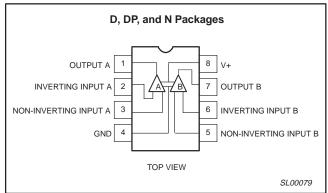


Figure 1. Pin configuration.

EQUIVALENT CIRCUIT

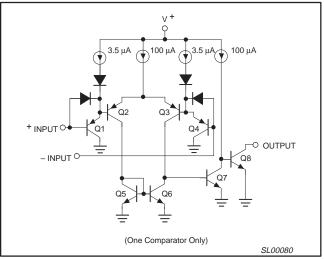


Figure 2. Equivalent circuit.

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
8-Pin Plastic Dual In-Line Package (DIP)	–55 °C to +125 °C	LM193AN	SOT97-1
8-Pin Plastic Small Outline (SO) Package	–25 °C to +85 °C	LM293D	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	–25 °C to +85 °C	LM293N	SOT97-1
8-Pin Plastic Small Outline (SO) Package	–25 °C to +85 °C	LM293AD	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	–25 °C to +85 °C	LM293AN	SOT97-1
8-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM393D	SOT96-1
8-Pin Plastic Thin Shrink Small Outline Package (TSSOP)	0 °C to +70 °C	LM393DP	SOT505-1
8-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM393N	SOT97-1
8-Pin Plastic Small Outline (SO) Package	0 °C to +70 °C	LM393AD	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	0 °C to +70 °C	LM393AN	SOT97-1
8-Pin Plastic Small Outline (SO) Package	–40 °C to +125 °C	LM2903D	SOT96-1
8-Pin Plastic Dual In-Line Package (DIP)	–40 °C to +125 °C	LM2903N	SOT97-1
8-Pin Plastic Thin Shrink Small Outline Package (TSSOP)	–40 °C to +125 °C	LM2903DP	SOT505-1

LM193A/293/A/393/A/2903

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V _{CC}	Supply voltage	32 or ±16	V _{DC}
	Differential input voltage	32	V _{DC}
VIN	Input voltage	-0.3 to +32	V _{DC}
PD	Maximum power dissipation, T _{amb} = 25 °C (still-air) ¹ N package D package DP package	1160 780 714	mW mW mW
	Output short-circuit to ground ²	Continuous	
I _{IN}	Input current (V _{IN} < -0.3 V _{DC}) ³	50	mA
T _{amb}	Operating temperature range LM193A LM293/293A LM393/393A LM2903	-55 to +125 -25 to +85 0 to +70 -40 to +125	ວໍ ວໍ ວຸ
T _{stg}	Storage temperature range	-65 to +150	°C
T _{sld}	Lead soldering temperature (10 sec max)	230	°C

NOTES:

1. Derate above 25 °C, at the following rates: N package at 9.3 mW/°C

D package at 6.2 mW/°C

DP package at 5.72 mW/°C

Short circuits from the output to V+ can cause excessive heating and eventual destruction. The maximum output current is approximately 20 mA independent of the magnitude of V+.

3. This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V_{DC}.

LM193A/293/A/393/A/2903

Low power dual voltage comparator

DC AND AC ELECTRICAL CHARACTERISTICS

 $V+=5 V_{DC}, LM193A: -55 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM293/293A: -25 \ ^{\circ}C \ T_{amb} \leq +85 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ LM2903: -40 \ ^{\circ}C \ T_{amb} \leq +125 \ ^{\circ}C, \ unless \ otherwise \ specified. \ unless \ otherwise \ specified. \ unless \ otherwise \ specified. \ unless \ otherwise \ unless \ otherwise \ specified. \ unless \ otherwise \ unless \ u$

evudoi		TERT CONDITIONS	LM193A			LM293A/393A			LM2903			UNIT
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
V	Input offect veltors?	T _{amb} = 25 °C		±1.0	±2.0		±1.0	±2.0		±2.0	±7.0	mV
V _{OS}	Input offset voltage ²	Over temp.			±4.0			±4.0		±9	±15	mV
Maria	Input common-mode	T _{amb} = 25 °C	0		V+-1.5	0		V+-1.5	0		V+-1.5	V
V _{CM}	voltage range ^{3, 6}	Over temp.	0		V+-2.0	0		V+-2.0	0		V+-2.0	V
V _{IDR}	Differential input voltage ¹	Keep all V _{IN} ≥ 0 V _{DC} (or V– if needed)			V+			V+			V+	V
		I _{IN(+)} or I _{IN(-)} with output in linear range										
IBIAS	Input bias current ⁴	T _{amb} = 25 °C		25	100		25	250		25	250	nA
		Over temp.			300			400		200	500	nA
I _{OS}	Input offset current	I _{IN(+)} − I _{IN(−)} T _{amb} = 25 °C		±3.0	±25		±5.0	±50		±5	±50	nA
-03		Over temp.			±100			±150		±50	±200	nA
I _{OL}	Output sink current	$V_{IN(-)} \ge 1 V_{DC}; V_{IN(+)} = 0;$ $V_O \le 1.5 V_{DC}$ $T_{amb} = 25 \ ^{\circ}C$	6.0	16		6.0	16		6.0	16		mA
		$V_0 = 5 V_{DC}; T_{amb} = 25 °C$		0.1			0.1			0.1		nA
	Output leakage current	V _{IN(+)} ≥1V _{DC} ; V _{IN(-)} =0; V _O = 30 V _{DC} ; Over temp.			1.0			1.0			1.0	μΑ
I _{CC}	Supply current	$R_L = \infty$ on both comparators; $T_{amb} = 25 \text{ °C}$		0.8	1		0.8	1		0.8	1	mA
		$R_L = \infty$ on both comparators; V+ = 30 V		1	2.5		1	2.5		1	2.5	mA
A _V	Voltage gain	R _L ≥ 15 kΩ; V+ = 15 V _{DC} ; T _{amb} = 25 °C	50	200		50	200		25	100		V/mV
V _{OL}	Saturation voltage	$\label{eq:VIN(-)} \begin{array}{l} V_{IN(-)} \geq 1 \ V_{DC}; \\ V_{IN(+)} = 0; \ I_{SINK} \leq 4 \ mA \\ T_{amb} = 25 \ ^{\circ}C \\ Over \ temp. \end{array}$		250	400 700		250	400 700		400	400 700	mV mV
t _{LSR}	Large-signal response time	$\label{eq:VIN} \begin{array}{l} V_{IN} = TTL \ logic \ swing, \\ V_{REF} = 1.4 \ V_{DC}; \\ V_{RL} = 5 \ V_{DC}; \\ R_{L} = 5.1 \ k\Omega; \\ T_{amb} = 25 \ ^{\circ}C \end{array}$		300			300			300		ns
t _R	Response time ⁵	V _{RL} = 5 V _{DC} ; R _L = 5.1 kΩ ; T _{amb} = 25 °C		1.3			1.3			1.3		μs

LM193A/293/A/393/A/2903

DC ELECTRICAL CHARACTERISTICS (Continued)

 $V+=5 V_{DC}, LM193A: -55 °C T_{amb} \le +125 °C, unless otherwise specified. LM293/293A: -25 °C T_{amb} \le +85 °C, unless otherwise specified. LM293/393A: 0 °C T_{amb} \le +70 °C, unless otherwise specified. LM2903: -40 °C T_{amb} \le +125 °C, unless otherwise specified.$

	DADAMETED	TERT CONDITIONS		LINUT			
SYMBOL	PARAMETER	TEST CONDITIONS	Min Typ		Max		
V _{OS}	Input offset voltage ²	T _{amb} = 25 °C Over temp.		±2.0	±5.0 ±9.0	mV mV	
V _{CM}	Input common-mode voltage range ^{3, 6}	T _{amb} = 25 °C Over temp.	0 0		V+-1.5 V+-2.0	V V	
V _{IDR}	Differential input voltage ¹	Keep all $V_{IN} \ge 0 V_{DC}$ (or V– if needed)			V+	V	
I _{BIAS}	Input bias current ⁴	$I_{IN(+)}$ or $I_{IN(-)}$ with output in linear range $T_{amb} = 25 \text{ °C}$ Over temp.		25	250 400	nA nA	
I _{OS}	Input offset current	I _{IN(+)} − I _{IN(−)} T _{amb} = 25 °C Over temp.		±5.0	±50 ±150	nA nA	
I _{OL}	Output sink current	$ \begin{array}{c} V_{IN(-)} \geq 1 \ V_{DC}; \ V_{IN(+)} = 0; \ V_O \leq 1.5 \ V_{DC} \\ T_{amb} = 25 \ ^\circ C \end{array} $	6.0	16		mA	
	Output leakage current	$V_{IN(+)} \ge 1 V_{DC}; V_{IN(-)} = 0,$ $V_O = 5 V_{DC}; T_{amb} = 25 \text{ °C}$ $V_O = 30 V_{DC}; \text{ over temp.}$		0.1	1.0	nA μA	
	Supply surrent	$R_L = \infty$ on both comparators, $T_{amb} = 25 \ ^{\circ}C$		0.8	1	mA	
Icc	Supply current	$R_L = \infty$ on both comparators; V+ = 30 V			2.5	mA	
A _V	Voltage gain	$R_L \ge 15 \text{ k}\Omega; \text{ V+} = 15 \text{ V}_{DC}$	50	200		V/mV	
V _{OL}	Saturation voltage	$\label{eq:VIN(-)} \begin{array}{l} V_{IN(-)} \geq 1 \ V_{DC}; \ V_{IN(+)} = 0; \ I_{SINK} \leq 4 \ mA \\ T_{amb} = 25 \ ^{\circ}C \\ Over \ temp. \end{array}$		250	400 700	mV mV	
t _{LSR}	Large signal response time	$\label{eq:VIN} \begin{array}{l} V_{IN} = TTL \mbox{ logic swing,} \\ V_{REF} = 1.4 \ V_{DC}; \ V_{RL} = 5 \ V_{DC}; \\ R_L = 5.1 \ \mbox{k}\Omega; \ T_{amb} = 25 \ \ ^{\circ}C \end{array}$		300		ns	
t _R	Response time ⁵	$V_{RL} = 5 V_{DC}; R_L = 5.1 k\Omega$ $T_{amb} = 25 °C$		1.3		μs	

NOTES:

 Positive excursions of input voltage may exceed the power supply level by 17 V. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than -0.3 V_{DC} (V_{DC} below the magnitude of the negative power supply, if used).

At output switch point, V_O ≈ 1.4 V_{DC}, R_S = 0 Ω with V+ from 5 V_{DC} to 30 V_{DC} and over the full input common-mode range (0 V_{DC} to V+ −1.5 V_{DC}).

 The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode voltage range is V+ –1.5 V, but either or both inputs can go to 30 V_{DC} without damage.

4. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.

5. The response time specified is for a 100 mV input step with a 5 mV overdrive.

 For input signals that exceed V_{CC}, only the over-driven comparator is affected. With a 5 V supply, V_{IN} should be limited to 25 V maximum, and a limiting resistor should be used on all inputs that might exceed the positive supply.

LM193A/293/A/393/A/2903

EQUIVALENT CIRCUIT

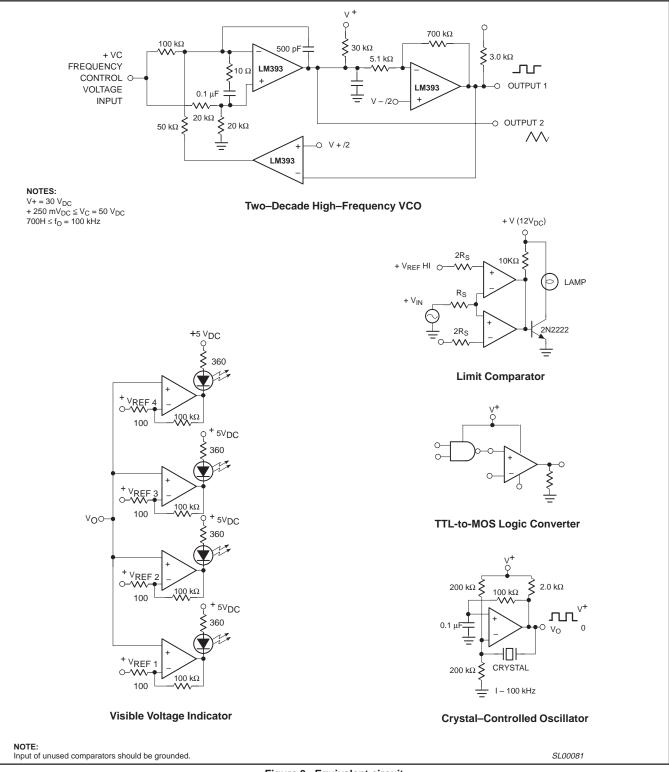


Figure 3. Equivalent circuit.

LM193A/293/A/393/A/2903

TYPICAL PERFORMANCE CHARACTERISTICS

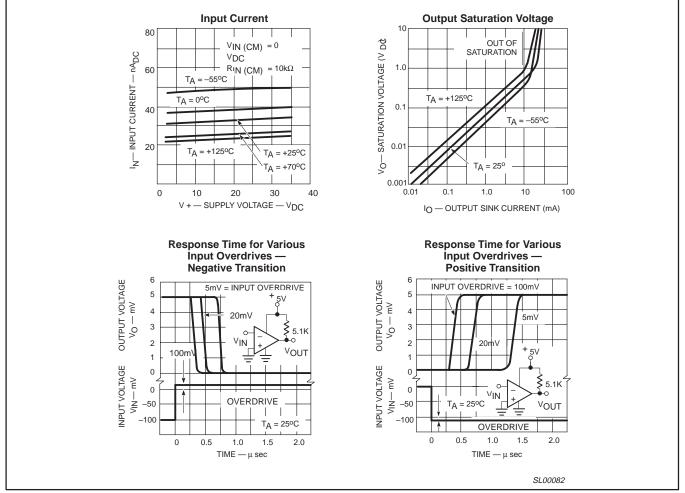
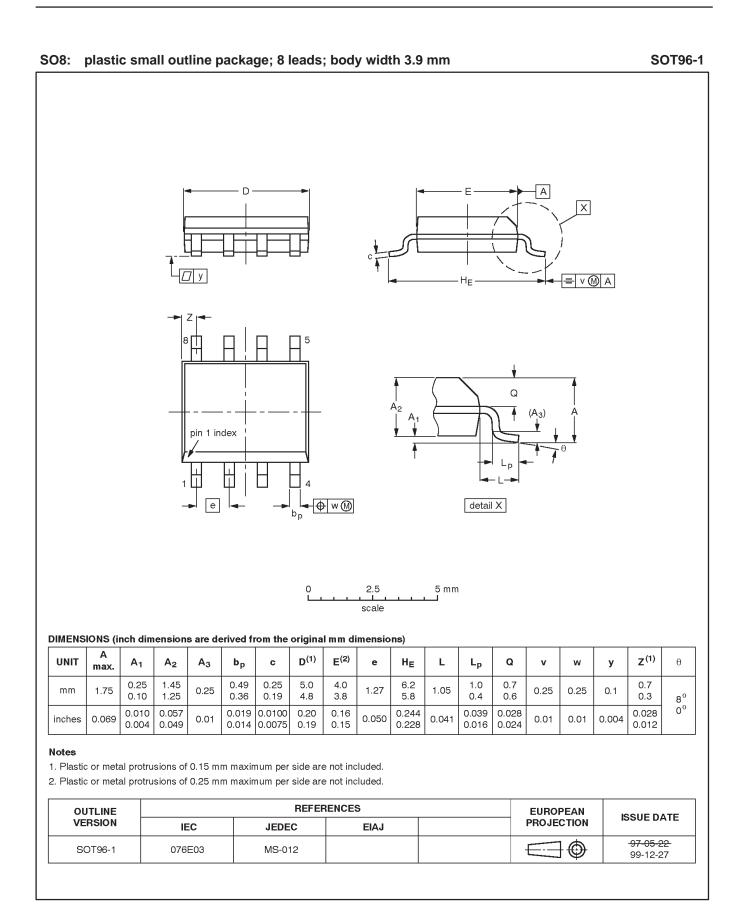


Figure 4. Typical performance characteristics.

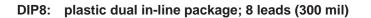
LM193A/293/A/393/A/2903

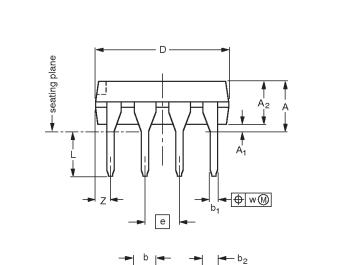


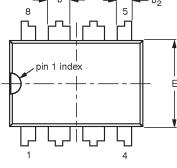
SOT97-1

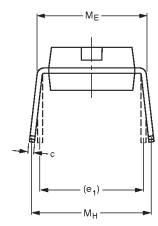
Low power dual voltage comparator

LM193A/293/A/393/A/2903









0			5			10 mm
		s	cal	е		

DIMENSIONS (inch dimensions are derived from the original mm dimensions)

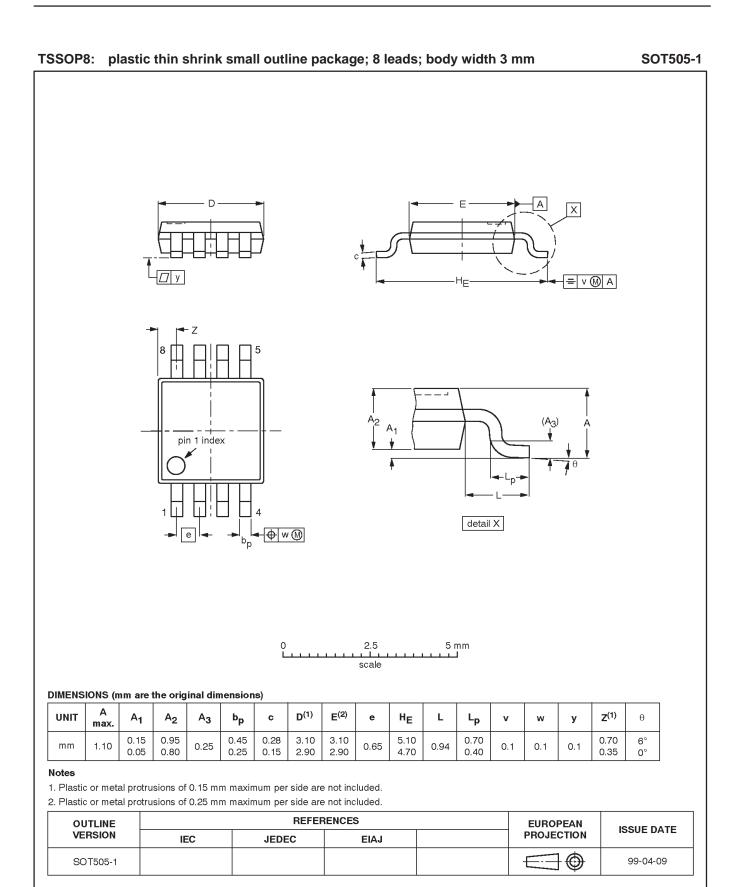
UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	с	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	Μ _E	м _н	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	1.15
inches	0.17	0.020	0.13	0.068 0.045	0.021 0.015	0.042 0.035	0.014 0.009	0.39 0.36	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.045

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT97-1	050G01	MO-001	SC-504-8			-95-02-04 99-12-27

LM193A/293/A/393/A/2903



LM193A/293/A/393/A/2903

NOTES

LM193A/293/A/393/A/2903

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
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